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HMC252QS24

GaAs MMIC SP6T NON-REFLECTIVE SWITCH, DC - 3.0 GHz

Typical Applications

The HMC252QS24 is ideal for:

- Base Station
- CATV / DBS
- MMDS & WirelessLAN
- Test Equipment

Features

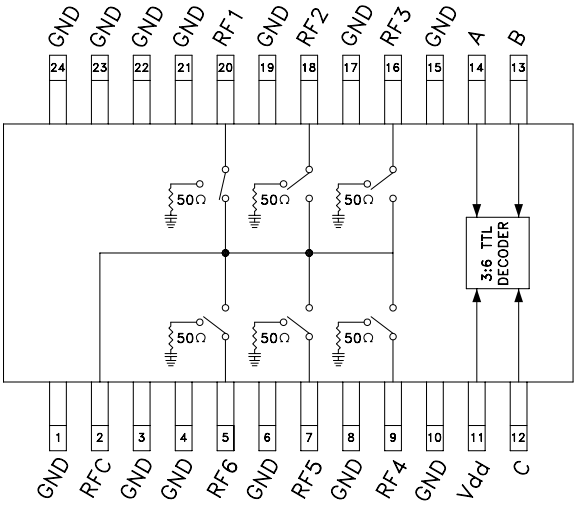
Low Insertion Loss (2 GHz): 0.9 dB

Single Positive Supply: Vdd = +5V

Integrated 3:6 TTL Decoder

24 Lead QSOP Package

Functional Diagram



General Description

The HMC252QS24 is a low-cost non-reflective SP6T switch in a 24-lead QSOP package featuring wideband operation from DC to 3.0 GHz. The switch offers a single positive bias and true TTL/CMOS compatibility. A 3:6 decoder is integrated on the switch requiring only 3 control lines and a positive bias to select each path. The HMC252QS24 SP6T replaces multiple configurations of SP4T and SPDT MMIC switches and logic drivers.

Electrical Specifications, T_A = +25° C, For TTL Control and Vdd = +5V in a 50 Ohm System

Parameter	Frequency	Min.	Typ.	Max.	Units
Insertion Loss	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz		0.8 0.9 1.0 1.3	1.2 1.3 1.5 1.8	dB dB dB dB
Isolation	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz	38 32 29 26	41 35 32 29		dB dB dB dB
Return Loss "On State"	DC - 2.5 GHz DC - 3.0 GHz	14 7	18 12		dB dB
Return Loss RF1-6 "Off State"	0.3 - 3.0 GHz 0.5 - 2.5 GHz	8 11	12 15		dB dB
Input Power for 1dB Compression	0.3 - 3.0 GHz	21	24		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone)	0.3 - 3.0 GHz	42	46		dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)	0.3 - 3.0 GHz		 35 120		 ns ns

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
12 Elizabeth Drive, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
Order Online at www.hittite.com

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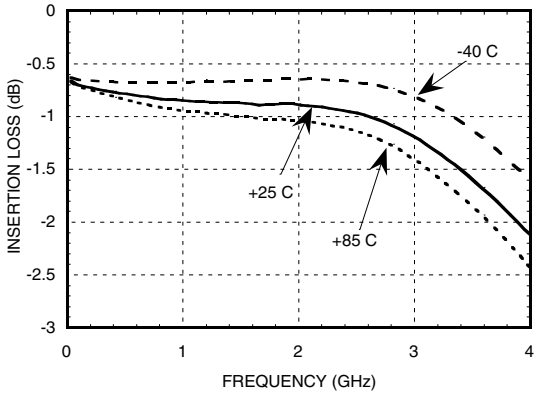
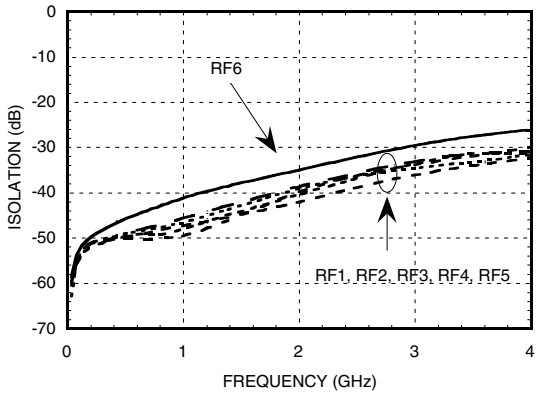
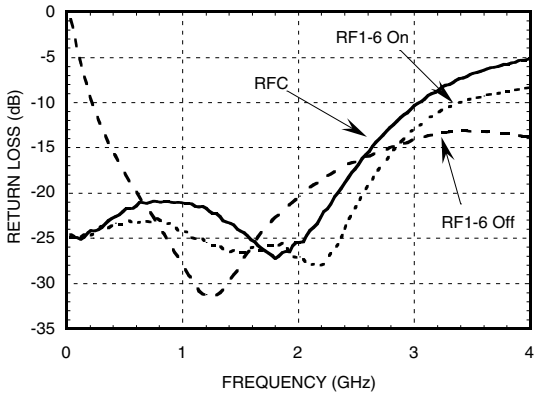
Insertion Loss



Isolation



Return Loss



Bias Voltage & Current

Vdd Range = +5.0 Vdc ± 10%		
Vdd (Vdc)	Idd (Typ.) (mA)	Idd (Max.) (mA)
+5.0	5.0	8.0

TTL/CMOS Control Voltages

State	Bias Condition
Low	0 to +0.8 Vdc @ 5uA Typ.
High	+2.0 to +5.0 Vdc @ 70 uA Typ.

Truth Table

Control Input			Signal Path State
A	B	C	RFCOM to:
LOW	LOW	LOW	RF1
HIGH	LOW	LOW	RF2
LOW	HIGH	LOW	RF3
HIGH	HIGH	LOW	RF4
LOW	LOW	HIGH	RF5
HIGH	LOW	HIGH	RF6
LOW	HIGH	HIGH	ALL OFF
HIGH	HIGH	HIGH	ALL OFF

NOTE:
1. DC Blocking capacitors are required at ports RFC and RF1, 2, 3, 4, 5, 6.
2. Input is reflective when “ALL OFF” state is selected.

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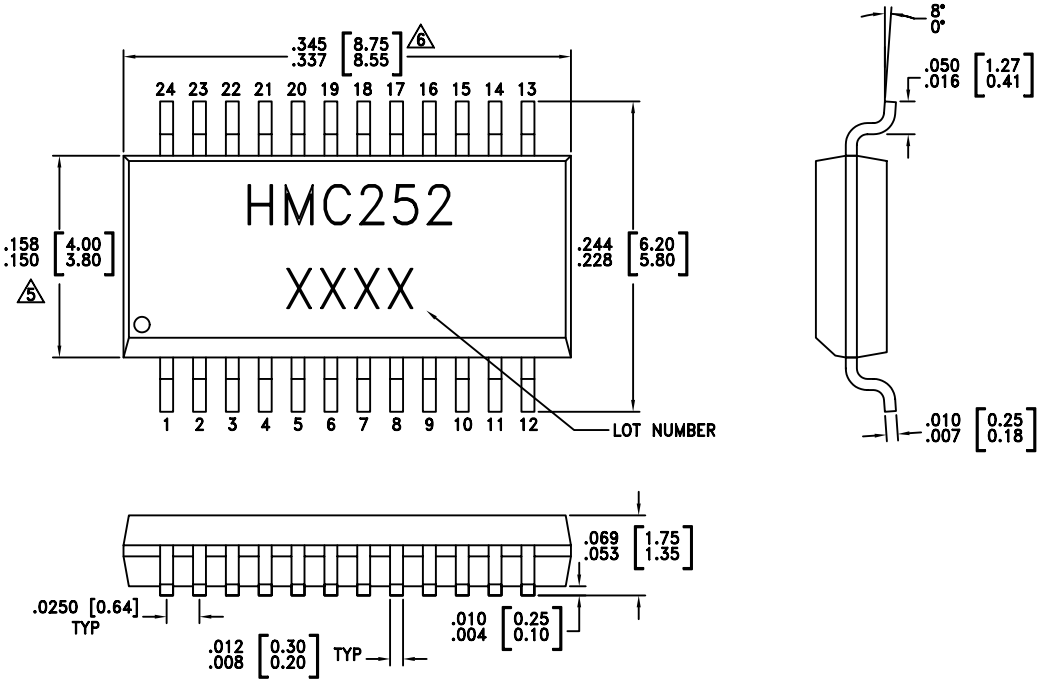
Absolute Maximum Ratings

Bias Voltage Range (Port Vdd)	+7.0 Vdc
Control Voltage Range (A, B, C)	-0.5V to Vdd +1 Vdc
Channel Temperature	150 °C
Thermal Resistance (Insertion Loss Path)	240 °C/W
Thermal Resistance (Terminated Path)	260 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Maximum Input Power Vdd = +5 Vdc	+20 dBm (0.05 - 0.5 GHz) +26 dBm (0.5 - 3.0 GHz)

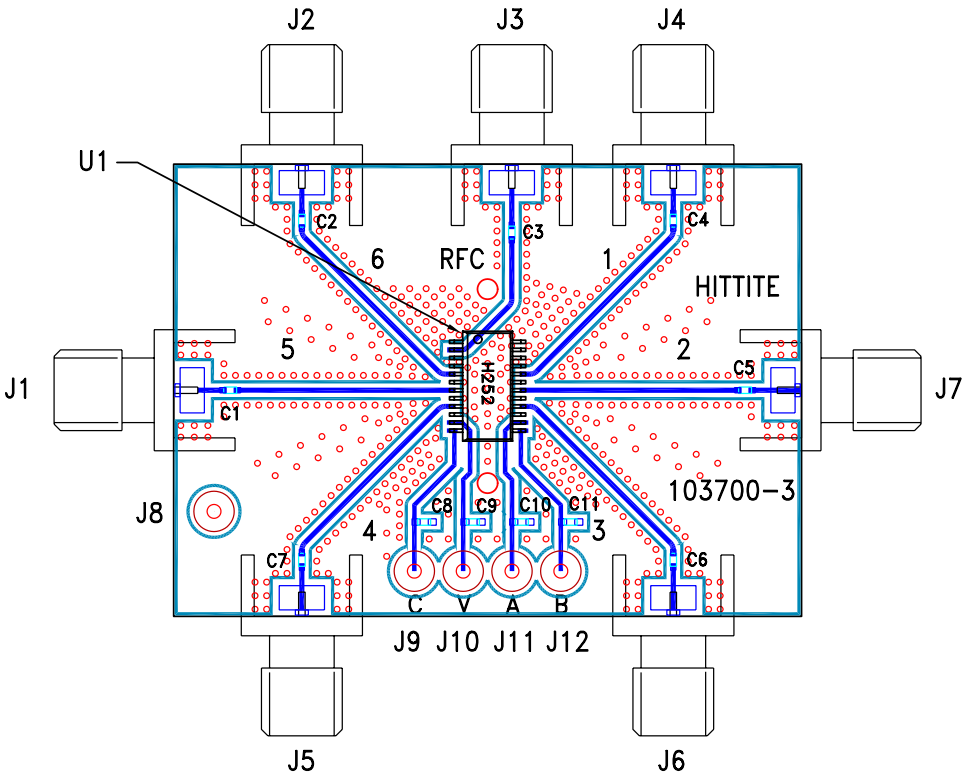
Outline Drawing



NOTES:

1. PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
2. LEADFRAME MATERIAL: COPPER ALLOY
3. LEADFRAME PLATING: Sn/Pb SOLDER
4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
5. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
6. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
7. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Evaluation Circuit Board



The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF ports should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown above. A sufficient number of VIA holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

List of Material

Item	Description
J1 - J7	PC Mount SMA Connector
J8 - J12	DC Pin
C1 - C7	100 pF Capacitor, 0402 Pkg.
C8 - C11	10,000 pF Capacitor, 0603 Pkg.
U1	HMC252QS24 SP8T Switch
PCB*	103700 Eval Board
* Circuit Board Material: Rogers 4350	